

MC14043B, MC14044B

CMOS MSI

Quad R–S Latches

The MC14043B and MC14044B quad R–S latches are constructed with MOS P–Channel and N–Channel enhancement mode devices in a single monolithic structure. Each latch has an independent Q output and set and reset inputs. The Q outputs are gated through three–state buffers having a common enable input. The outputs are enabled with a logical “1” or high on the enable input; a logical “0” or low disconnects the latch from the Q outputs, resulting in an open circuit at the Q outputs.

Features

- Double Diode Input Protection
- Three–State Outputs with Common Enable
- Outputs Capable of Driving Two Low–power TTL Loads or One Low–Power Schottky TTL Load Over the Rated Temperature Range
- Supply Voltage Range = 3.0 Vdc to 18 Vdc
- These Devices are Pb–Free and are RoHS Compliant

MAXIMUM RATINGS (Voltages Referenced to V_{SS})

| Symbol | Parameter | Value | Unit |
|-------------------|---|------------------------|------|
| V_{DD} | DC Supply Voltage Range | –0.5 to +18.0 | V |
| V_{in}, V_{out} | Input or Output Voltage Range (DC or Transient) | –0.5 to $V_{DD} + 0.5$ | V |
| I_{in}, I_{out} | Input or Output Current (DC or Transient) per Pin | ± 10 | mA |
| P_D | Power Dissipation, per Package (Note 1) | 500 | mW |
| T_A | Ambient Temperature Range | –55 to +125 | °C |
| T_{stg} | Storage Temperature Range | –65 to +150 | °C |
| T_L | Lead Temperature (8–Second Soldering) | 260 | °C |

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

1. Temperature Derating:

Plastic “P and D/DW” Packages: – 7.0 mW/°C From 65°C To 125°C

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high–impedance circuit. For proper operation, V_{in} and V_{out} should be constrained to the range $V_{SS} \leq (V_{in} \text{ or } V_{out}) \leq V_{DD}$.

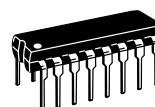
Unused inputs must always be tied to an appropriate logic voltage level (e.g., either V_{SS} or V_{DD}). Unused outputs must be left open.



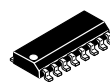
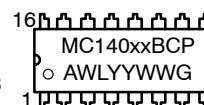
ON Semiconductor®

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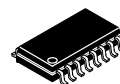
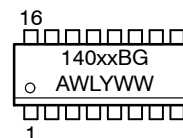
MARKING DIAGRAMS



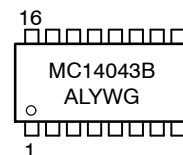
PDIP–16
P SUFFIX
CASE 648



SOIC–16
D SUFFIX
CASE 751B



SOEIAJ–16
F SUFFIX
CASE 966



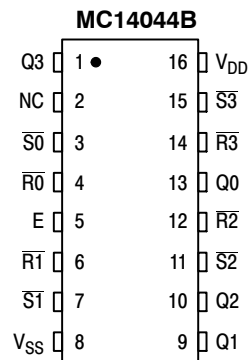
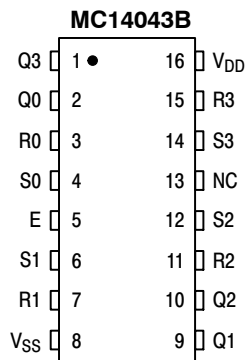
xx = Specific Device Code
A = Assembly Location
WL, L = Wafer Lot
YY, Y = Year
WW, W = Work Week
G = Pb–Free Indicator

ORDERING INFORMATION

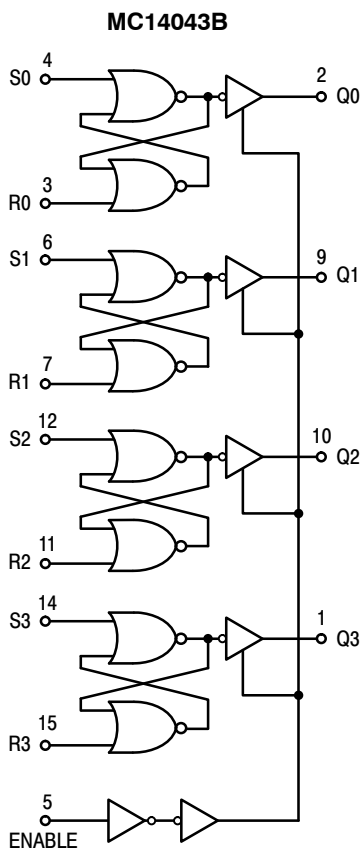
See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

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PIN ASSIGNMENT



NC = NO CONNECTION

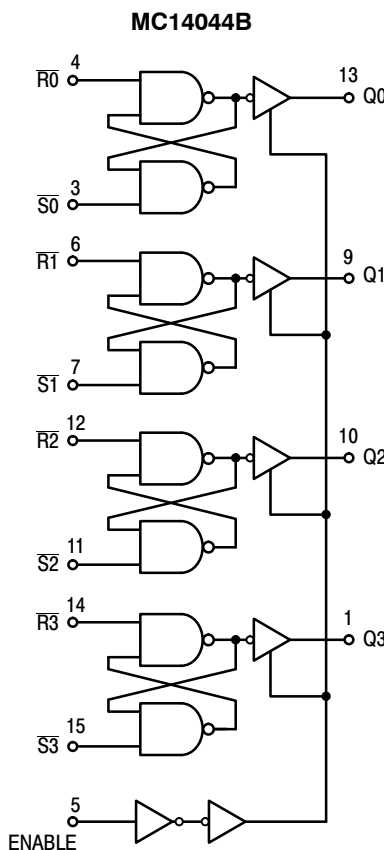


V_{DD} = PIN 16
V_{SS} = PIN 8
NC = PIN 13

TRUTH TABLE

| S | R | E | Q |
|---|---|---|----------------|
| X | X | 0 | High Impedance |
| 0 | 0 | 1 | No Change |
| 0 | 1 | 1 | 0 |
| 1 | 0 | 1 | 1 |
| 1 | 1 | 1 | 1 |

X = Don't Care



V_{DD} = PIN 16
V_{SS} = PIN 8
NC = PIN 2

TRUTH TABLE

| S | R | E | Q |
|---|---|---|----------------|
| X | X | 0 | High Impedance |
| 0 | 0 | 1 | 0 |
| 0 | 1 | 1 | 1 |
| 1 | 0 | 1 | 0 |
| 1 | 1 | 1 | No Change |

X = Don't Care

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ELECTRICAL CHARACTERISTICS (Voltages Referenced to V_{SS})

| Characteristic | Symbol | V _{DD} Vdc | - 55°C | | 25°C | | | 125°C | | Unit | |
|--|-----------------|------------------------|--|-------|------|-----------------|-------|-------|-------|------|------|
| | | | Min | Max | Min | Typ (Note 2) | Max | Min | Max | | |
| Output Voltage V _{in} = V _{DD} or 0 | "0" Level | V _{OL} | 5.0 | - | 0.05 | - | 0 | 0.05 | - | 0.05 | Vdc |
| | | | 10 | - | 0.05 | - | 0 | 0.05 | - | 0.05 | |
| 15 | | | - | 0.05 | - | 0 | 0.05 | - | 0.05 | | |
| V _{in} = 0 or V _{DD} | "1" Level | V _{OH} | 5.0 | 4.95 | - | 4.95 | 5.0 | - | 4.95 | - | Vdc |
| | | | 10 | 9.95 | - | 9.95 | 10 | - | 9.95 | - | |
| | | | 15 | 14.95 | - | 14.95 | 15 | - | 14.95 | - | |
| Input Voltage (V _O = 4.5 or 0.5 Vdc) (V _O = 9.0 or 1.0 Vdc) (V _O = 13.5 or 1.5 Vdc) | "0" Level | V _{IL} | 5.0 | - | 1.5 | - | 2.25 | 1.5 | - | 1.5 | Vdc |
| | | | 10 | - | 3.0 | - | 4.50 | 3.0 | - | 3.0 | |
| 15 | | | - | 4.0 | - | 6.75 | 4.0 | - | 4.0 | | |
| (V _O = 0.5 or 4.5 Vdc) (V _O = 1.0 or 9.0 Vdc) (V _O = 1.5 or 13.5 Vdc) | "1" Level | V _{IH} | 5.0 | 3.5 | - | 3.5 | 2.75 | - | 3.5 | - | Vdc |
| | | | 10 | 7.0 | - | 7.0 | 5.50 | - | 7.0 | - | |
| | | | 15 | 11 | - | 11 | 8.25 | - | 11 | - | |
| Output Drive Current (V _{OH} = 2.5 Vdc) (V _{OH} = 4.6 Vdc) (V _{OH} = 9.5 Vdc) (V _{OH} = 13.5 Vdc) | Source | I _{OH} | 5.0 | -3.0 | - | -2.4 | -4.2 | - | -1.7 | - | mAdc |
| | | | 5.0 | -0.64 | - | -0.51 | -0.88 | - | -0.36 | - | |
| 10 | | | -1.6 | - | -1.3 | -2.25 | - | -0.9 | - | | |
| 15 | | | -4.2 | - | -3.4 | -8.8 | - | -2.4 | - | | |
| (V _{OL} = 0.4 Vdc) (V _{OL} = 0.5 Vdc) (V _{OL} = 1.5 Vdc) | Sink | I _{OL} | 5.0 | 0.64 | - | 0.51 | 0.88 | - | 0.36 | - | mAdc |
| | | | 10 | 1.6 | - | 1.3 | 2.25 | - | 0.9 | - | |
| | | | 15 | 4.2 | - | 3.4 | 8.8 | - | 2.4 | - | |
| Input Current | I _{in} | 15 | - | ±0.1 | - | ±0.00001 | ±0.1 | - | ±1.0 | μAdc | |
| Input Capacitance (V _{in} = 0) | C _{in} | - | - | - | - | 5.0 | 7.5 | - | - | pF | |
| Quiescent Current (Per Package) | I _{DD} | 5.0 | - | 1.0 | - | 0.002 | 1.0 | - | 30 | μAdc | |
| | | 10 | - | 2.0 | - | 0.004 | 2.0 | - | 60 | | |
| | | 15 | - | 4.0 | - | 0.006 | 4.0 | - | 120 | | |
| Total Supply Current (Notes 3 & 4) (Dynamic plus Quiescent, Per Package) (C _L = 50 pF on all outputs all buffers switching) | I _T | 5.0 | I _T = (0.58 μA/kHz) f + I _{DD} | | | | | | | μAdc | |
| | | 10 | I _T = (1.15 μA/kHz) f + I _{DD} | | | | | | | | |
| | | 15 | I _T = (1.73 μA/kHz) f + I _{DD} | | | | | | | | |
| Three-State Output Leakage Current | I _{TL} | 15 | - | ± 0.1 | - | ± 0.0001 | ± 0.1 | - | ± 3.0 | μAdc | |

2. Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.

3. The formulas given are for the typical characteristics only at 25°C.

4. To calculate total supply current at loads other than 50 pF:

$$I_T(C_L) = I_T(50 \text{ pF}) + (C_L - 50) \text{ Vfk}$$

where: I_T is in μA (per package), C_L in pF, V = (V_{DD} - V_{SS}) in volts, f in kHz is input frequency, and k = 0.004.

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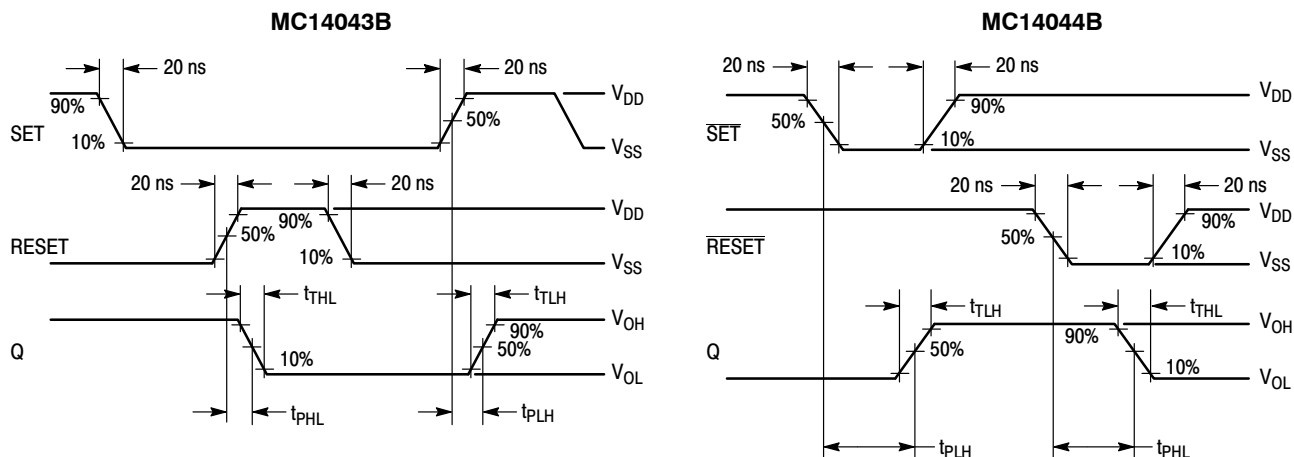
SWITCHING CHARACTERISTICS (Note 5) ($C_L = 50 \text{ pF}$, $T_A = 25^\circ\text{C}$)

| Characteristic | Symbol | V_{DD} Vdc | Min | Typ (Note 6) | Max | Unit |
|--|--|--|--------------------------------|--|--|----------------------|
| Output Rise Time $t_{TLH} = (1.35 \text{ ns/pF}) C_L + 32.5 \text{ ns}$ $t_{TLH} = (0.60 \text{ ns/pF}) C_L + 20 \text{ ns}$ $t_{TLH} = (0.40 \text{ ns/pF}) C_L + 20 \text{ ns}$ | t_{TLH} | 5.0 10 15 | – – – | 100 50 40 | 200 100 80 | ns |
| Output Fall Time $t_{THL} = (1.35 \text{ ns/pF}) C_L + 32.5 \text{ ns}$ $t_{THL} = (0.60 \text{ ns/pF}) C_L + 20 \text{ ns}$ $t_{THL} = (0.40 \text{ ns/pF}) C_L + 20 \text{ ns}$ | t_{THL} | 5.0 10 15 | – – – | 100 50 40 | 200 100 80 | ns |
| Propagation Delay Time $t_{PLH} = (0.90 \text{ ns/pF}) C_L + 130 \text{ ns}$ $t_{PLH} = (0.36 \text{ ns/pF}) C_L + 57 \text{ ns}$ $t_{PLH} = (0.26 \text{ ns/pF}) C_L + 47 \text{ ns}$ $t_{PHL} = (0.90 \text{ ns/pF}) C_L + 130 \text{ ns}$ $t_{PHL} = (0.90 \text{ ns/pF}) C_L + 57 \text{ ns}$ $t_{PHL} = (0.26 \text{ ns/pF}) C_L + 47 \text{ ns}$ | t_{PLH} t_{PHL} | 5.0 10 15 5.0 10 15 | – – – – – – | 175 75 60 175 75 60 | 350 175 120 350 175 120 | ns ns |
| Set, $\overline{\text{Set}}$ Pulse Width | t_W | 5.0 10 15 | 200 100 70 | 80 40 30 | – – – | ns |
| Reset, $\overline{\text{Reset}}$ Pulse Width | t_W | 5.0 10 15 | 200 100 70 | 80 40 30 | – – – | ns |
| Three-State Enable/Disable Delay | t_{PLZ} , t_{PHZ} , t_{PZL} , t_{PZH} | 5.0 10 15 | – – – | 150 80 55 | 300 160 110 | ns |

5. The formulas given are for the typical characteristics only at 25°C .

6. Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.

AC WAVEFORMS

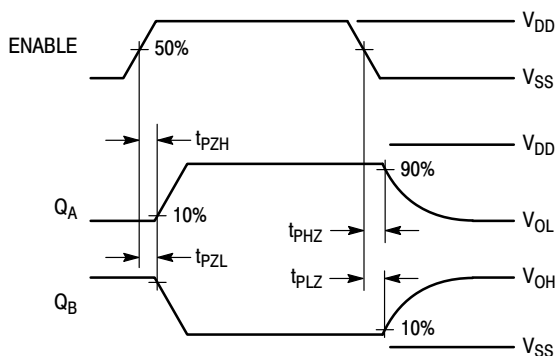
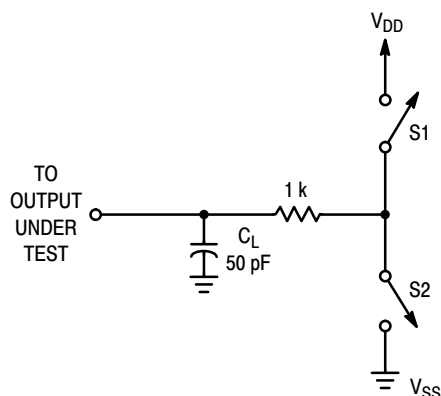


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THREE-STATE ENABLE/DISABLE DELAYS

Set, Reset, Enable, and Switch Conditions for 3-State Tests

| Test | Enable | S1 | S2 | Q | MC14043B | | MC14044B | |
|-----------|--------|--------|--------|---|----------|----------|-----------|-----------|
| | | | | | S | R | \bar{S} | \bar{R} |
| t_{PZH} | | Open | Closed | A | V_{DD} | V_{SS} | V_{SS} | V_{DD} |
| t_{PZL} | | Closed | Open | B | V_{SS} | V_{DD} | V_{DD} | V_{SS} |
| t_{PHZ} | | Open | Closed | A | V_{DD} | V_{SS} | V_{SS} | V_{DD} |
| t_{PLZ} | | Closed | Open | B | V_{SS} | V_{DD} | V_{DD} | V_{SS} |



ORDERING INFORMATION

| Device | Package | Shipping† |
|----------------|----------------------|--------------------------|
| MC14043BCPG | PDIP-16 (Pb-Free) | 500 Units / Rail |
| MC14043BDG | SOIC-16 (Pb-Free) | 48 Units / Rail |
| NLV14043BDG* | | |
| MC14043BDR2G | SOIC-16 (Pb-Free) | 2500 Units / Tape & Reel |
| NLV14043BDR2G* | | |
| MC14043BFELG | SOEIAJ-16 | 2000 Units / Tape & Reel |
| MC14044BCPG | PDIP-16 (Pb-Free) | 500 Units / Rail |
| MC14044BDG | SOIC-16 (Pb-Free) | 48 Units / Rail |
| MC14044BDR2G | SOIC-16 (Pb-Free) | 2500 Units / Tape & Reel |

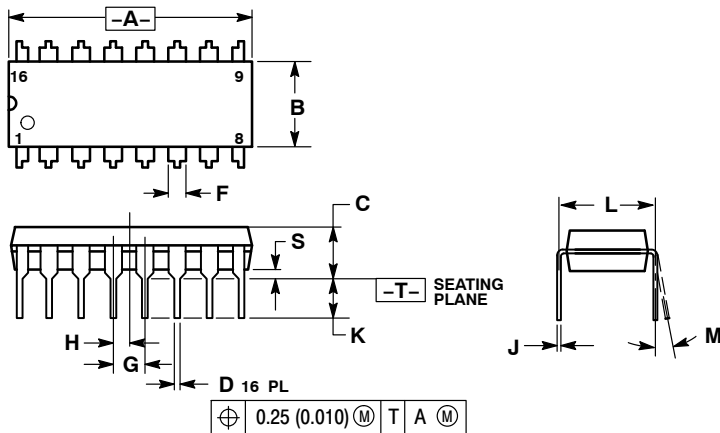
†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

*NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.

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PACKAGE DIMENSIONS

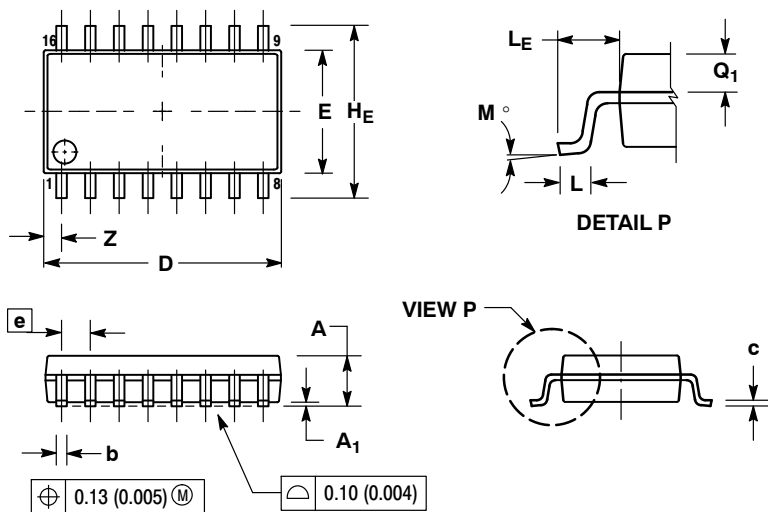
PDIP-16
P SUFFIX
PLASTIC DIP PACKAGE
CASE 648-08
ISSUE T



- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
 4. DIMENSION B DOES NOT INCLUDE MOLD FLASH.
 5. ROUNDED CORNERS OPTIONAL.

| DIM | INCHES | | MILLIMETERS | |
|-----|-----------|-------|-------------|-------|
| | MIN | MAX | MIN | MAX |
| A | 0.740 | 0.770 | 18.80 | 19.55 |
| B | 0.250 | 0.270 | 6.35 | 6.85 |
| C | 0.145 | 0.175 | 3.69 | 4.44 |
| D | 0.015 | 0.021 | 0.39 | 0.53 |
| F | 0.040 | 0.70 | 1.02 | 1.77 |
| G | 0.100 BSC | | 2.54 BSC | |
| H | 0.050 BSC | | 1.27 BSC | |
| J | 0.008 | 0.015 | 0.21 | 0.38 |
| K | 0.110 | 0.130 | 2.80 | 3.30 |
| L | 0.295 | 0.305 | 7.50 | 7.74 |
| M | 0° | 10° | 0° | 10° |
| S | 0.020 | 0.040 | 0.51 | 1.01 |

SOEIAJ-16
F SUFFIX
PLASTIC EIAJ SOIC PACKAGE
CASE 966-01
ISSUE A



- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETER.
 3. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS AND ARE MEASURED AT THE PARTING LINE. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
 4. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
 5. THE LEAD WIDTH DIMENSION (b) DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE LEAD WIDTH DIMENSION AT MAXIMUM MATERIAL CONDITION. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT. MINIMUM SPACE BETWEEN PROTRUSIONS AND ADJACENT LEAD TO BE 0.46 (0.018).

| DIM | MILLIMETERS | | INCHES | |
|----------------|-------------|-------|-----------|-------|
| | MIN | MAX | MIN | MAX |
| A | --- | 2.05 | --- | 0.081 |
| A ₁ | 0.05 | 0.20 | 0.002 | 0.008 |
| b | 0.35 | 0.50 | 0.014 | 0.020 |
| c | 0.10 | 0.20 | 0.007 | 0.011 |
| D | 9.90 | 10.50 | 0.390 | 0.413 |
| E | 5.10 | 5.45 | 0.201 | 0.215 |
| e | 1.27 BSC | | 0.050 BSC | |
| H _E | 7.40 | 8.20 | 0.291 | 0.323 |
| L | 0.50 | 0.85 | 0.020 | 0.033 |
| L _E | 1.10 | 1.50 | 0.043 | 0.059 |
| M | 0° | 10° | 0° | 10° |
| Q ₁ | 0.70 | 0.90 | 0.028 | 0.035 |
| Z | --- | 0.78 | --- | 0.031 |

Компания «Life Electronics» занимается поставками электронных компонентов импортного и отечественного производства от производителей и со складов крупных дистрибьюторов Европы, Америки и Азии.

С конца 2013 года компания активно расширяет линейку поставок компонентов по направлению коаксиальный кабель, кварцевые генераторы и конденсаторы (керамические, пленочные, электролитические), за счёт заключения дистрибьюторских договоров

Мы предлагаем:

- Конкурентоспособные цены и скидки постоянным клиентам.
- Специальные условия для постоянных клиентов.
- Подбор аналогов.
- Поставку компонентов в любых объемах, удовлетворяющих вашим потребностям.
- Приемлемые сроки поставки, возможна ускоренная поставка.
- Доставку товара в любую точку России и стран СНГ.
- Комплексную поставку.
- Работу по проектам и поставку образцов.
- Формирование склада под заказчика.
- Сертификаты соответствия на поставляемую продукцию (по желанию клиента).
- Тестирование поставляемой продукции.
- Поставку компонентов, требующих военную и космическую приемку.
- Входной контроль качества.
- Наличие сертификата ISO.

В составе нашей компании организован Конструкторский отдел, призванный помогать разработчикам, и инженерам.

Конструкторский отдел помогает осуществить:

- Регистрацию проекта у производителя компонентов.
- Техническую поддержку проекта.
- Защиту от снятия компонента с производства.
- Оценку стоимости проекта по компонентам.
- Изготовление тестовой платы монтаж и пусконаладочные работы.



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